

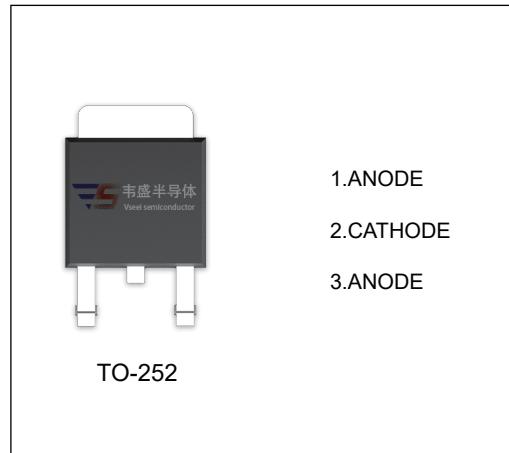
SBDD20150CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	20 (2×10) A
V_{RRM}	150 V
T_j	150 °C
V_{F(typ)}	0.71V (@Tj=125°C)

FEATURES

- Low Power Loss, High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{RRM}	Peak repetitive reverse voltage	150	V
V _{RWM}	Working peak reverse voltage		
V _R	DC blocking voltage		
V _{R(RMS)}	RMS reverse voltage	105	V
I _O	Average rectified output current	20	A
I _{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	150	A
R _{θJC}	Thermal resistance from junction to case	5.0	°C/W
R _{θJA}	Thermal resistance from junction to ambient	100	°C/W
T _j	Junction temperature	150	°C
T _{stg}	Storage temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	V _(BR)	I _R =0.1mA	150			V
Reverse current	I _R	V _R =150V	T _j =25°C	2.0	100	uA
			T _j =125°C	2.0		mA
Forward voltage	V _F	I _F =5A	T _j =25°C	0.76		V
			T _j =125°C	0.64		V
		I _F =10A	T _j =25°C	0.83	0.9	V
			T _j =125°C	0.71		V

*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

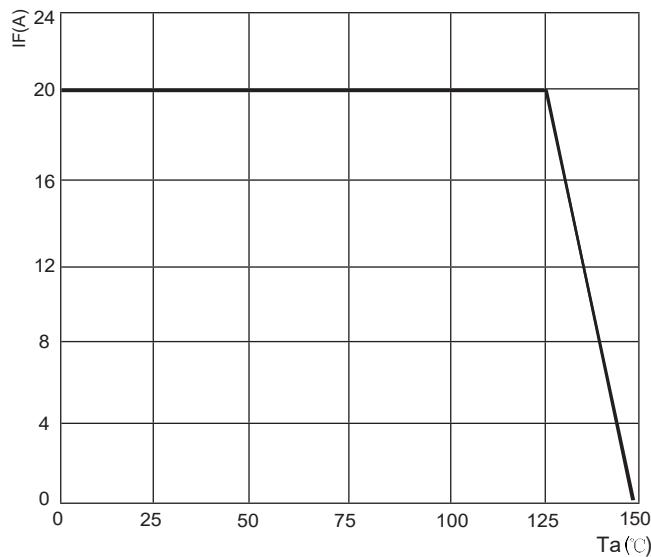


FIG.2: TYPICAL FORWARD CHARACTERISTICS

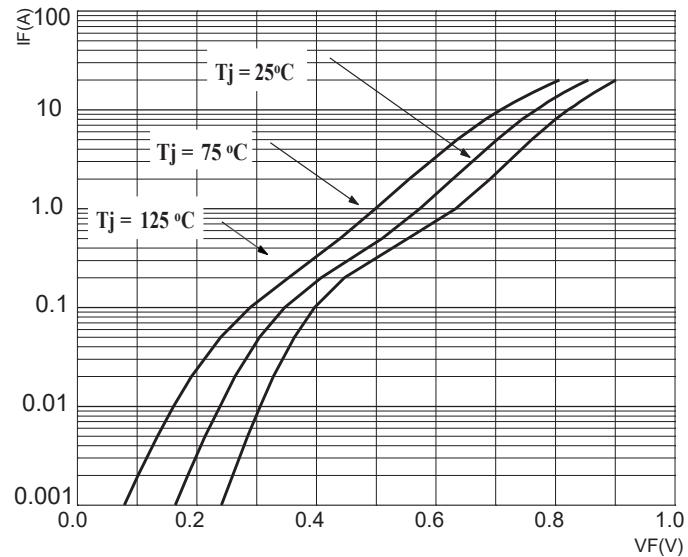


FIG.3: TOTAL CAPACITANCE DERATING CURVE

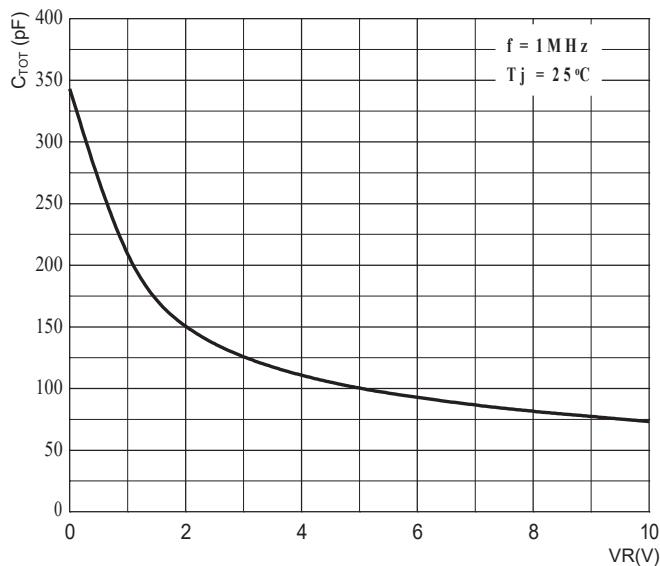


FIG.4: TYPICAL REVERSE CHARACTERISTICS

